TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL TYPE (PCT PROCESS) (DARLINGTON)

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PRINTER DRIVE, CORE DRIVE AND LED DRIVE APPLICATIONS LOW FREQUENCY AMPLIFIER APPLICATIONS

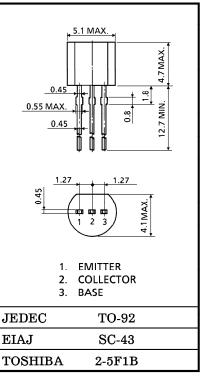
• High DC Current Gain : $h_{FE(1)}=5000 \text{ (Min.) (I}_{C}=10\text{mA})$: $h_{FE(2)}=10000 \text{ (Min.) (I}_{C}=100\text{mA})$

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Collector-Base Voltage		V _{CBO}	40	V	
Collector-Emitter Voltage		v_{CEO}	40	V	
Emitter-Base Voltage		$ ule{V_{\mathrm{EBO}}}$	10	V	
Collector Current	DC	$I_{\mathbf{C}}$	300	mA	
	Pulsed (Note)	ICP	500		
Base Current		$I_{\mathbf{B}}$	10	mA	
Collector Power Dissipation		PC	400	mW	
Junction Temperature		T_{j}	125	°C	
Storage Temperature Range		$\mathrm{T_{stg}}$	-55~125	°C	

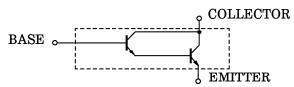
Note: Pulse Width≦10ms, Duty Cycle≦10%

Unit in mm



Weight: 0.21g

EQUIVALENT CIRCUIT

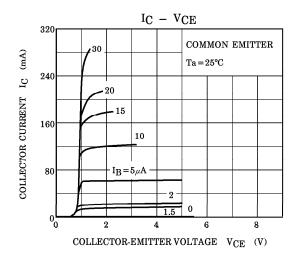


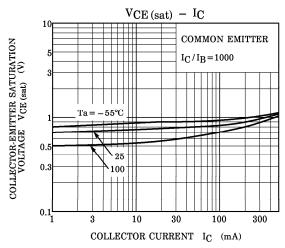
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

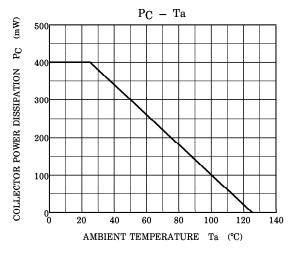
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I _{CBO}	$V_{CB} = 40V, I_{E} = 0$	_	_	0.1	μ A
Emitter Cut-off Current	$I_{ m EBO}$	$V_{EB}=8V, I_C=0$	_	_	0.1	μ A
DC Current Gain	$_{ m h_{FE}(1)}$	$V_{ ext{CE}} = 5V, I_{ ext{C}} = 10 \text{mA}$	5000	_	_	
	h _{FE (2)}	$V_{CE}=2V$, $I_{C}=100$ mA	10000	_	_	
Collector-Emitter Saturation Voltage	VCE (sat)	$I_{\rm C} = 300 {\rm mA}, \ I_{\rm B} = 0.3 {\rm mA}$		0.9	1.3	V
Base-Emitter Voltage	$V_{ m BE}$	$V_{CE}=2V, I_{C}=100mA$	_	1.25	1.6	V

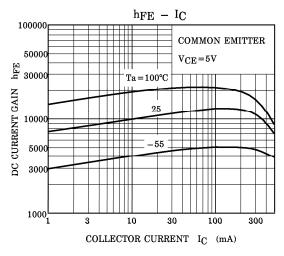
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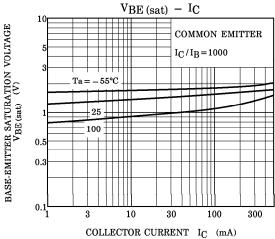
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